NSN 5961-00-481-7663

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-481-7663

Inclosure Material:

Metal

Overall Length:

0.460 inches

Overall Diameter:

0.667 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0